Technical Data
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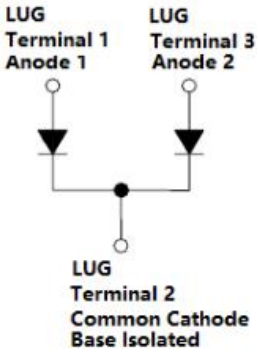
408CNQ060 SCHOTTKY RECTIFIER

PRM4 (Non-Isolated)

Features

- 150℃ T_J operation
- Center tap module
- High purity, high temperature epoxy encapsulation for
- enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Base plate: Nickel plated; Terminals: Nickel plated
- The terminal hardware is supplied with the module.
- The mounting hardware is not supplied. Recommended is the use of ¼-20 or M6 screws with spring washer.
- This is a Pb − Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- High current switching power supply
- Plating power supply
- Free-Wheeling diodes
- Reverse battery protection
- Converters
- UPS System
- Welding

Maximum Ratings(limiting values, at 25 °C unless otherwise specified)

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	-	60	V
Average Rectified Forward Current	$I_{F(AV)}$	50% duty cycle @T_C =109°C, rectangular wave form	200(Per Leg) 400(Per Device)	A
Peak One Cycle Non-Repetitive Surge Current (Per Leg)	I_{FSM}	8.3 ms, half Sine pulse	3960	A
Non-Repetitive Avalanche Energy(Peg Leg)	E_{AS}	T_J=25℃,I_{AS}=1A,L=30mH	15	mJ
Repetitive Avalanche Current (Peg Leg)	I_{AR}	Current decaying linearly to zero in 1 μsec Frequency limited by T_J max. V_A=1.5×V_R typical	1	A

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Electrical Characteristics:

Characteristics	Symbol	Condition	Typ.	Max.	Units
Forward Voltage Drop(Per Leg)*	V_{F1}	@ 200A, Pulse, T_J = 25 °C @ 400A, Pulse, T_J = 25 °C	0.61 0.78	0.68 0.83	V
	V_{F2}	@ 200A, Pulse, T_J = 125 °C @ 400A, Pulse, T_J = 125 °C	0.56 0.71	0.59 0.76	V
Reverse Current(Per Leg)*	I_{R1}	@V_R = rated V_R, T_J = 25 °C	0.8	2.2	mA
	I_{R2}	@V_R = rated V_R, T_J = 125 °C	133	600	mA
Junction Capacitance(Per leg)	C_T	@V_R = 5V, T_C = 25 °C f_{SIG} = 1MHz	6890	10000	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/µs

* Pulse width < 300 µs, duty cycle < 2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification		Units
Junction Temperature	T_J	-	-55 to +150		°C
Storage Temperature	T_{stg}	-	-55 to +150		°C
Typical Thermal Resistance Junction to Case(Per leg)	$R_{\theta JC}$	DC operation	0.40		°C/W
Typical Thermal Resistance Junction to Case(Per package)	$R_{\theta JC}$	DC operation	0.20		°C/W
Typical Thermal Resistance, case to Heat Sink	$R_{\theta cs}$	Mounting surface, smooth and greased	0.08		°C/W
Mounting Torque	T_M	-	Mounting Torque	3.84(min) 4.80(max)	Nm
			Terminal Torque	2.35(min) 3.43(max)	
Approximate Weight	wt	-	91		g
Case Style	PRM4 Non-Isolated				

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Ratings and Characteristics Curves

Figure1
Typical Forward Characteristics

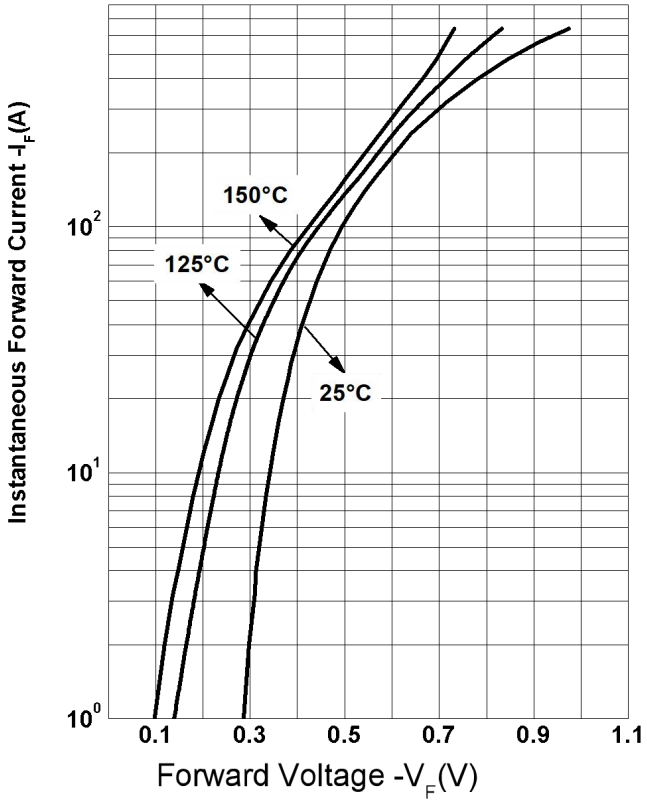


Figure 2
Typical Reverse Characteristics

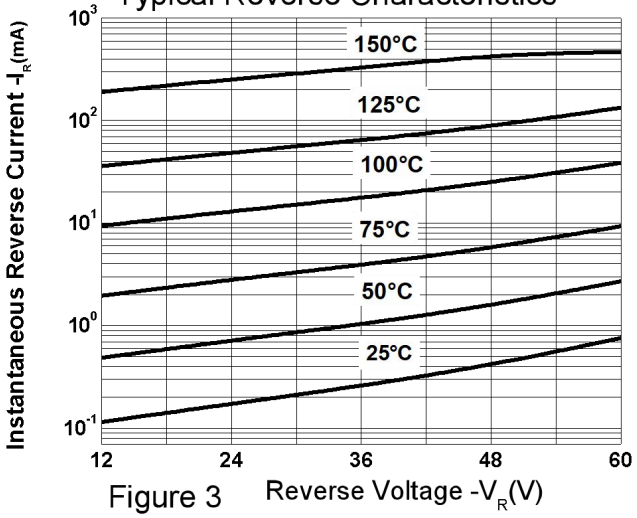
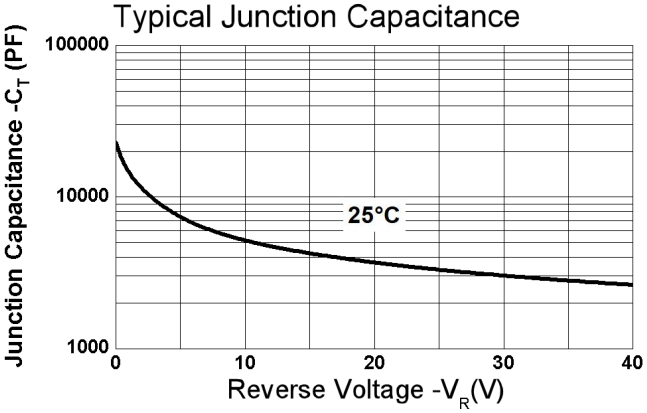
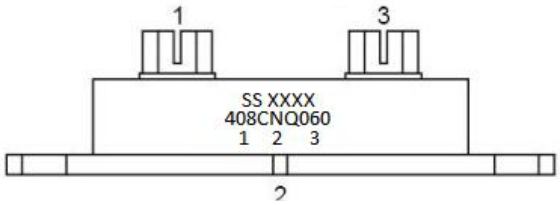


Figure 3
Typical Junction Capacitance



Marking Diagram



Where XXXX is YYWW

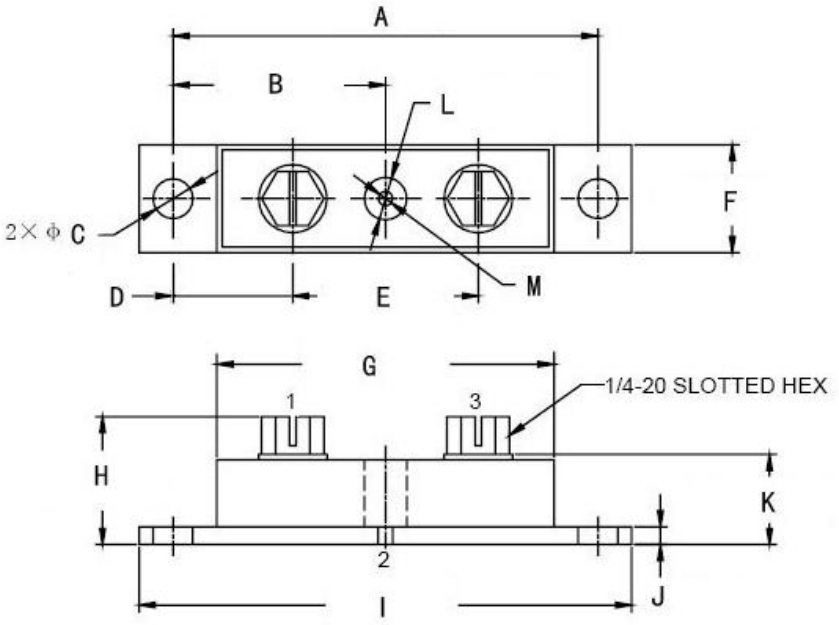
408CNQ060	= Part name
SS	= SS
YY	= Year
WW	= Week

Cautions: Molding resin
Epoxy resin UL:94V-0

Ordering Information

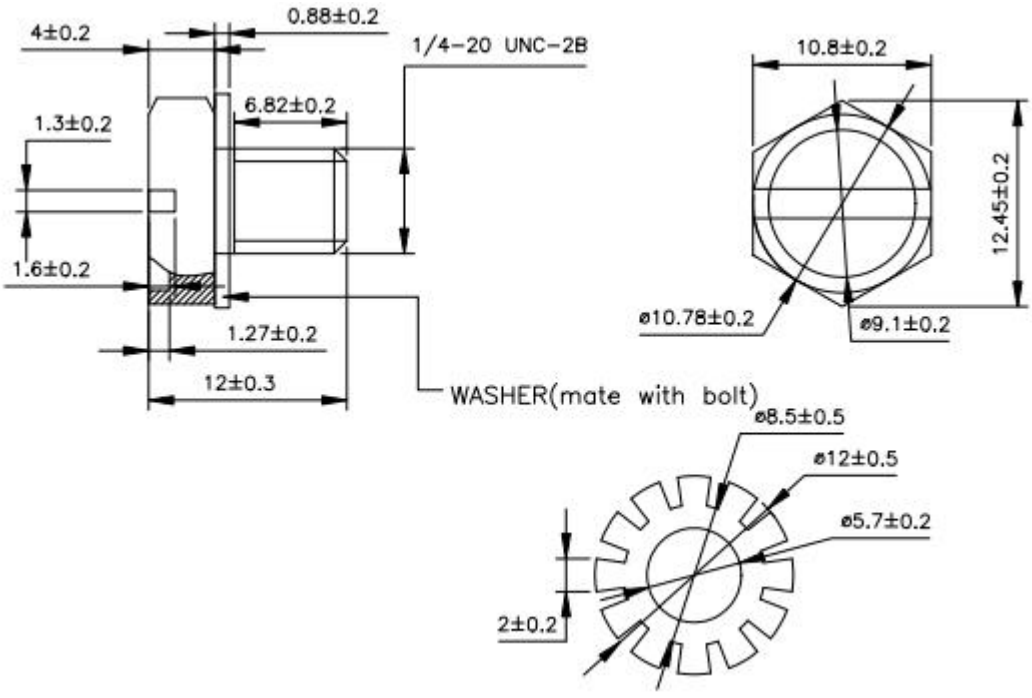
Device	Package	Shipping
408CNQ060	PRM4(Non- Isolated) (Pb-Free)	9 pcs/box

Mechanical Dimensions PRM4 Non-Isolated(Millimeters/Inches)



SYMBOL	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	78.74	81.28	3.100	3.200
B	37.47	42.55	1.475	1.675
C	6.89	7.69	0.271	0.303
D	19.51	24.59	0.768	0.968
E	33.02	38.10	1.300	1.500
F	17.78	20.32	0.700	0.800
G	60.96	64.77	2.400	2.550
H	17.26	23.25	0.680	0.915
I	90.17	92.71	3.550	3.650
J	3.02	3.68	0.119	0.145
K	14.30	16.15	0.563	0.636
L	9.27	10.79	0.365	0.425
M	4.37	5.28	0.172	0.208

1/4-20 screws (Millimeters)



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